Discrete POWER & Signal **Technologies**



NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	25	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	500	mA
TJ, Tsta	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

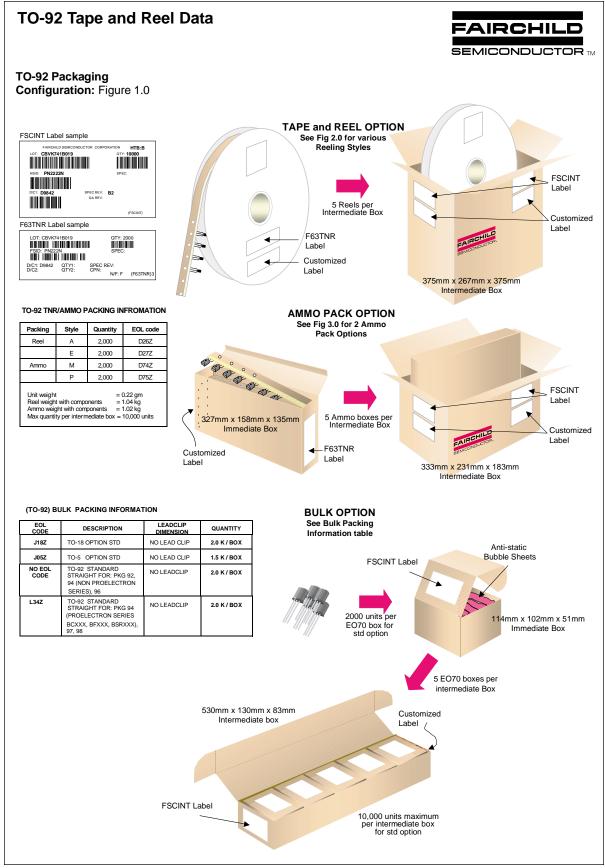
Symbol	Characteristic	Max	Units	
		2N3390 / 3391/A / 3392 / 3393		
P _D	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
R _{θJA}	Thermal Resistance, Junction to Ambient	200	°C/W	

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NPN General Purpose Amplifier

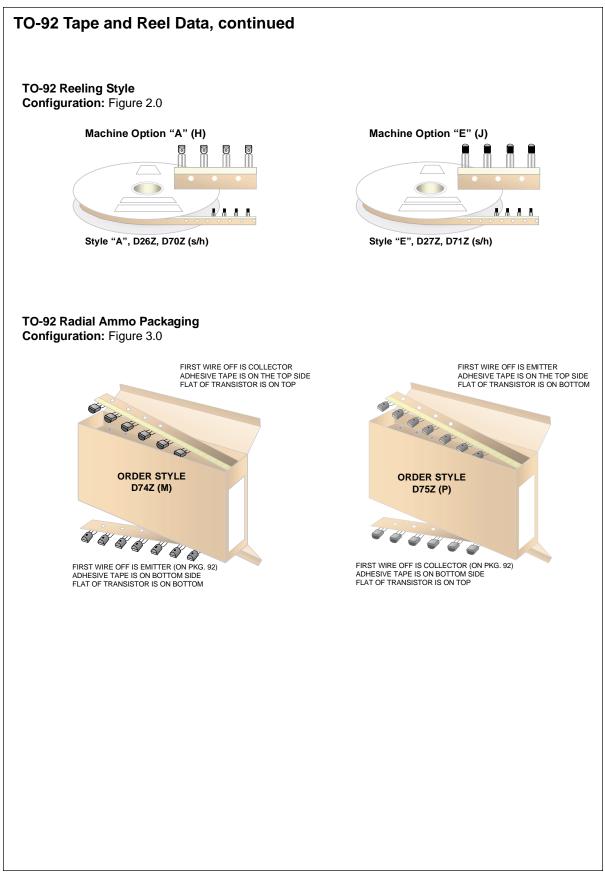
Symbol	Parameter	Test Conditions	Min	Max	Units
	·				
	RACTERISTICS			-	-
/ _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	25		V
/ _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	25		V
(BR)EBO	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	5.0		V
СВО	Collector-Cutoff Current	$V_{CB} = 18 \text{ V}, I_E = 0$		100	nA
EBO	Emitter-Cutoff Current	$V_{EB} = 5.0 \text{ V}, I_C = 0$		100	nA
	RACTERISTICS*				
	DC Current Gain	$V_{CE} = 4.5 \text{ V}, I_{C} = 2.0 \text{ mA}$			
		2N3390	400	800	
		2N3391/A 2N3392	250 150	500 300	
		2N3393	90	180	
١F	Noise Figure	f = 1.0 kHz 2N3390 2N3391/A 2N3392 2N3393 V _{CE} = 4.5 V, I _C = 100 μA,	400 250 150 90	1250 800 500 400	
NF	Noise Figure		90	400	
		$ \begin{array}{l} R_{G} = \ 500 \ \Omega, \textbf{2N3391A only} \\ B_{W} = 15.7 \ kHz \end{array} $		5.0	dB

2N3390 / 2N3391 / 2N3391A / 2N3392 / 2N3393

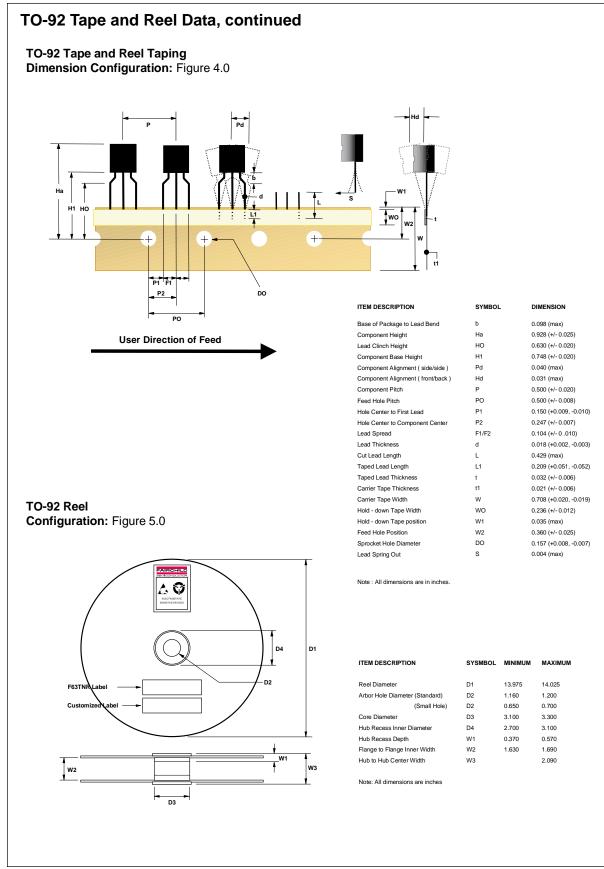


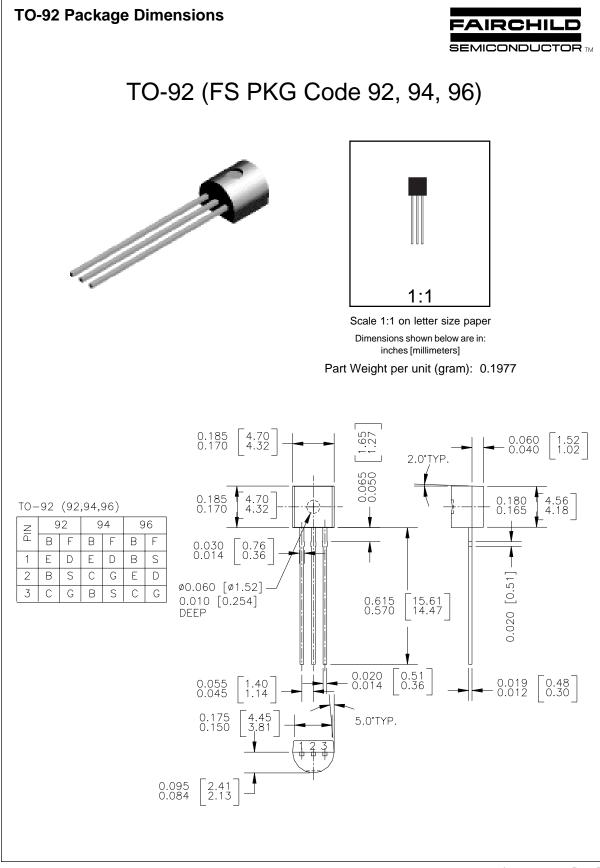
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Definition of Terms

Product Status	Definition		
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